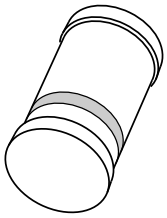
DATA SHEET



PRLL5817; PRLL5818; PRLL5819
Schottky barrier diodes

Product specification
Supersedes data of November 1993
File under Discrete Semiconductors, SC01

1996 May 03

Philips
Semiconductors

PHILIPS

Schottky barrier diodes PRLL5817; PRLL5818; PRLL5819

FEATURES

- Low switching losses
- Fast recovery time
- Guard ring protected
- Hermetically sealed glass SMD package.

APPLICATIONS

- Low power, switched-mode power supplies
- Rectifying
- Polarity protection.

DESCRIPTION

The PRLL5817 to PRLL5819 types are Schottky barrier diodes fabricated in planar technology, and encapsulated in SOD87 hermetically sealed glass SMD packages incorporating Implotec™(1) technology.

(1) Implotec is a trademark of Philips.

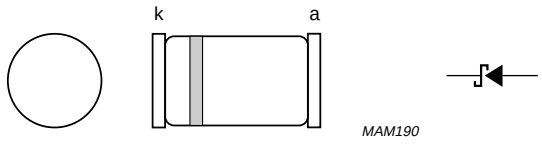


Fig.1 Simplified outline (SOD87) and symbol.

MARKING

TYPE NUMBER	MARKING CODE
PRLL5817	817 PH
PRLL5818	818 PH
PRLL5819	819 PH

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage				
	PRLL5817		–	20	V
	PRLL5818		–	30	V
	PRLL5819		–	40	V
V_{RSM}	non-repetitive peak reverse voltage				
	PRLL5817		–	24	V
	PRLL5818		–	36	V
	PRLL5819		–	48	V
V_{RRM}	repetitive peak reverse voltage				
	PRLL5817		–	20	V
	PRLL5818		–	30	V
	PRLL5819		–	40	V
V_{RWM}	crest working reverse voltage				
	PRLL5817		–	20	V
	PRLL5818		–	30	V
	PRLL5819		–	40	V
$I_{F(AV)}$	average forward current	T_{amb} = 60 °C	–	1	A
I_{FSM}	non-repetitive peak forward current	t = 10 ms half sine wave; $T_j = T_{j\,max}$ prior to surge: V_R = 0	–	25	A
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature		–	125	°C

ELECTRICAL CHARACTERISTICS

T_{amb} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	see Fig.2				
	PRLL5817	I_F = 0.1 A	–	–	320	mV
		I_F = 1 A	–	–	450	mV
		I_F = 3 A	–	–	750	mV
V_F	forward voltage	see Fig.2				
	PRLL5818	I_F = 0.1 A	–	–	330	mV
		I_F = 1 A	–	–	550	mV
		I_F = 3 A	–	–	875	mV
V_F	forward voltage	see Fig.2				
	PRLL5819	I_F = 0.1 A	–	–	340	mV
		I_F = 1 A	–	–	600	mV
		I_F = 3 A	–	–	900	mV
I_R	reverse current	$V_R = V_{RRMmax}$; note 1	–	0.5	1	mA
		$V_R = V_{RRMmax}$; T_j = 100 °C	–	5	10	mA
C_d	diode capacitance	V_R = 4 V; f = 1 MHz				
	PRLL5817		–	70	–	pF
	PRLL5818		–	50	–	pF
	PRLL5819		–	50	–	pF

Note

1. Pulsed test: t_p = 300 μs; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	150	K/W

Note

1. Refer to SOD87 standard mounting conditions.

GRAPHICAL DATA

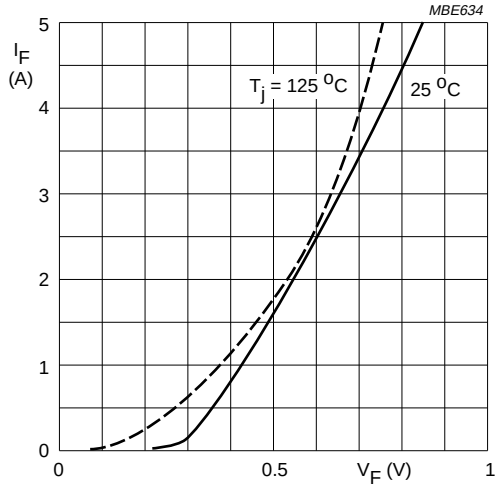


Fig.2 Typical forward voltage.

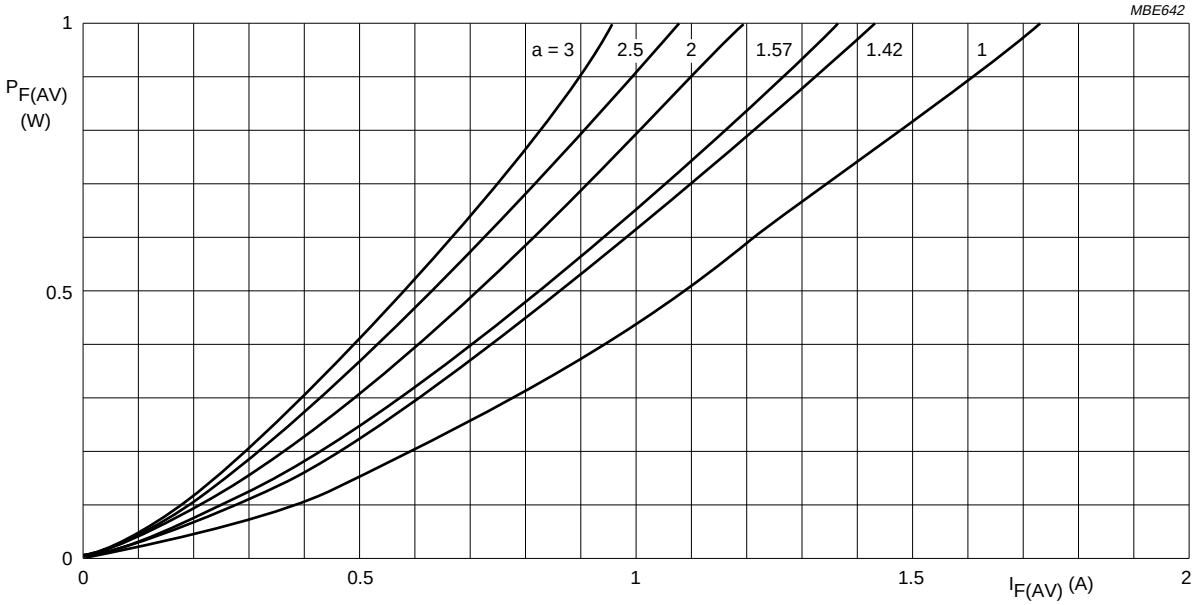


Fig.3 PRLL817. Maximum values steady state forward power dissipation as a function of the average forward current; a = $I_{F(RMS)}/I_{F(AV)}$.

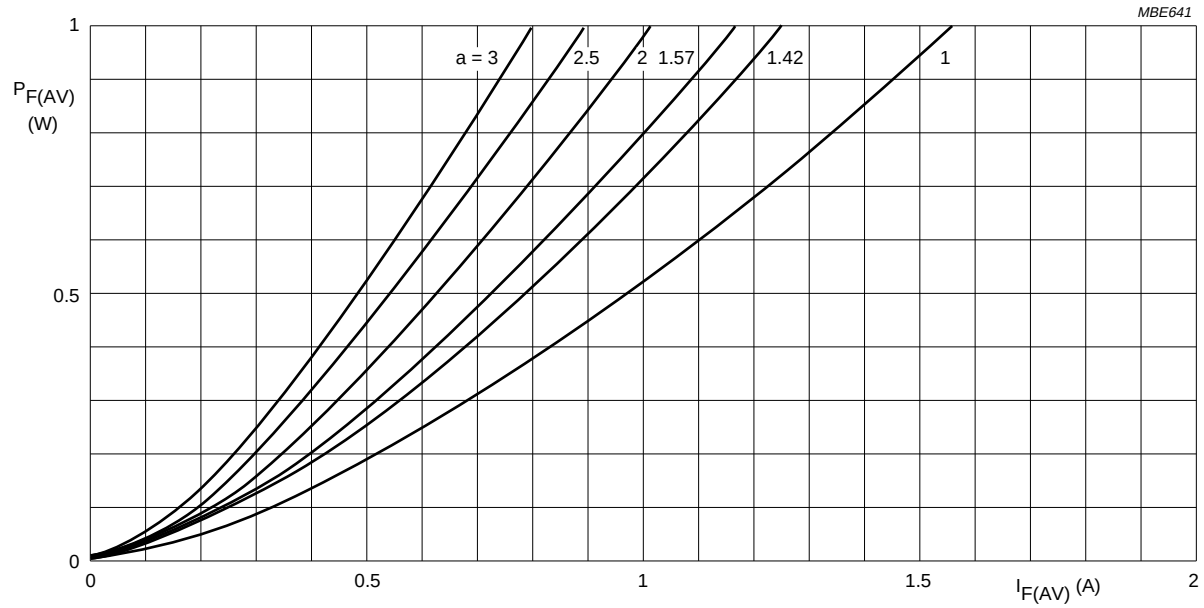


Fig.4 PRLL5818. Maximum values steady state forward power dissipation as a function of the average forward current; $a = I_{F(RMS)}/I_{F(AV)}$.

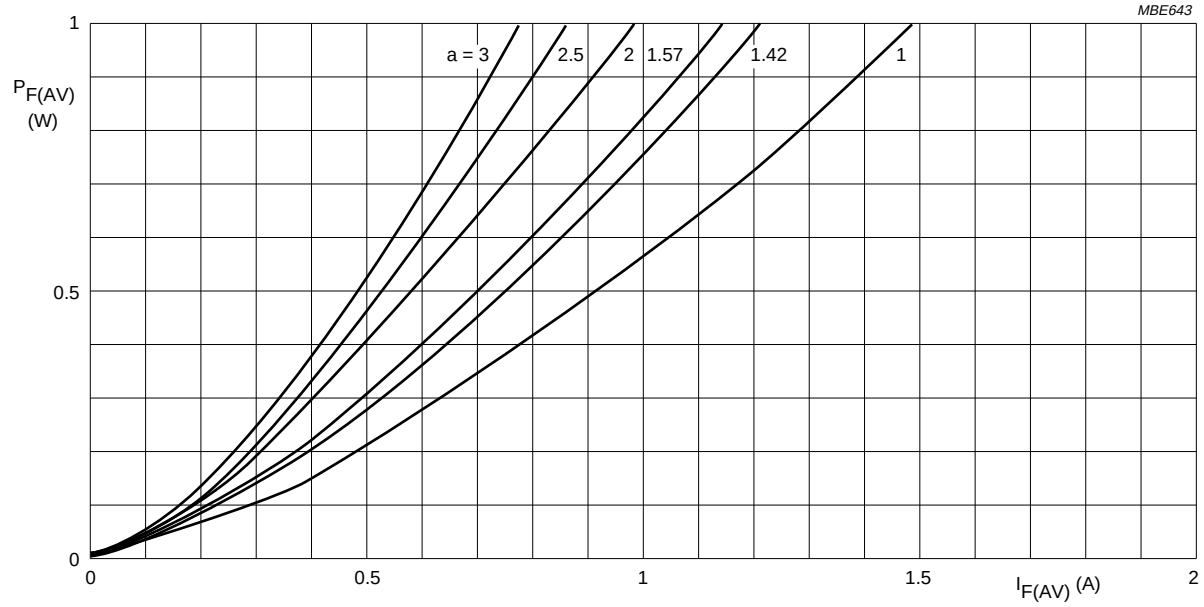


Fig.5 PRLL5819. Maximum values steady state forward power dissipation as a function of the average forward current; $a = I_{F(RMS)}/I_{F(AV)}$.

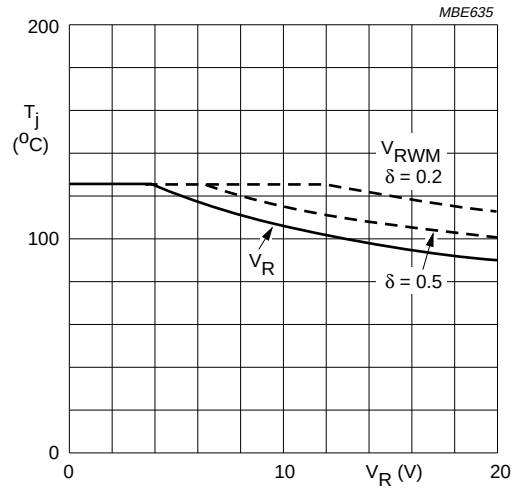


Fig.6 PRLL5817. Maximum permissible junction temperature as a function of reverse voltage; device mounted; refer to SOD87 standard mounting conditions.

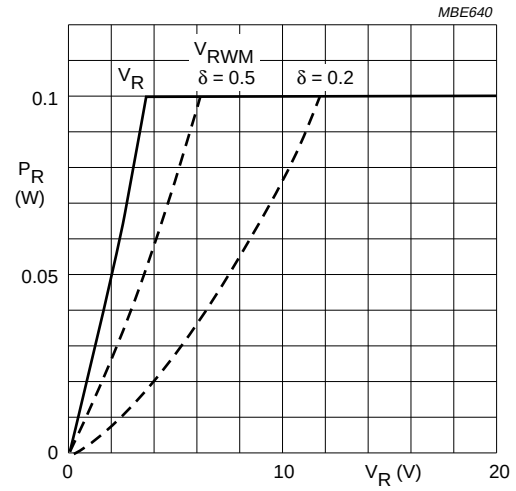


Fig.7 PRLL5817. Reverse power dissipation as a function of reverse voltage (max. values); device mounted; refer to SOD87 standard mounting conditions.

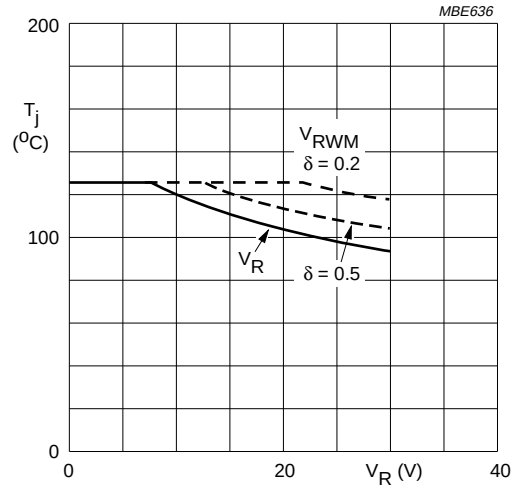


Fig.8 PRLL5818. Maximum permissible junction temperature as a function of reverse voltage; device mounted; refer to SOD87 standard mounting conditions.

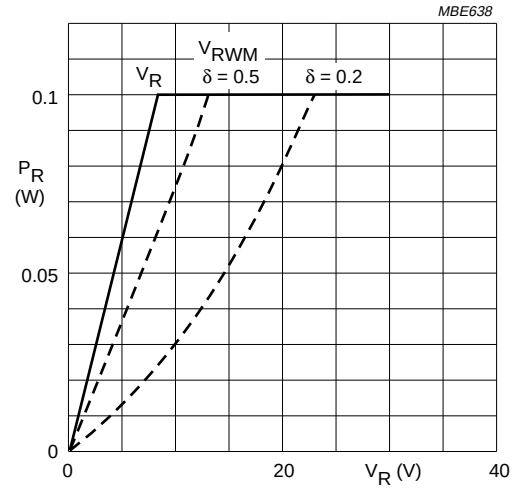


Fig.9 PRLL5818. Reverse power dissipation as a function of reverse voltage (max. values); device mounted; refer to SOD87 standard mounting conditions.

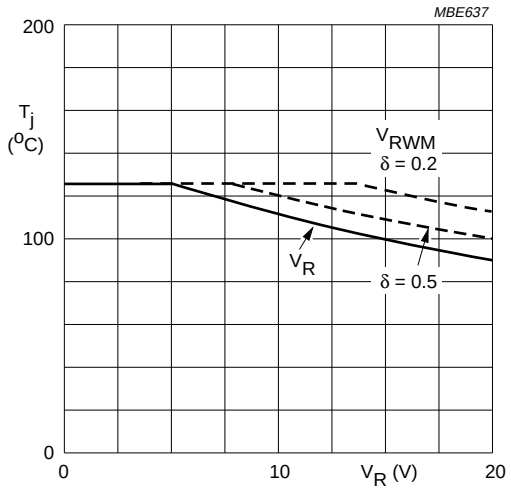


Fig.10 PRLL5819. Maximum permissible junction temperature as a function of reverse voltage; device mounted; refer to SOD87 standard mounting conditions.

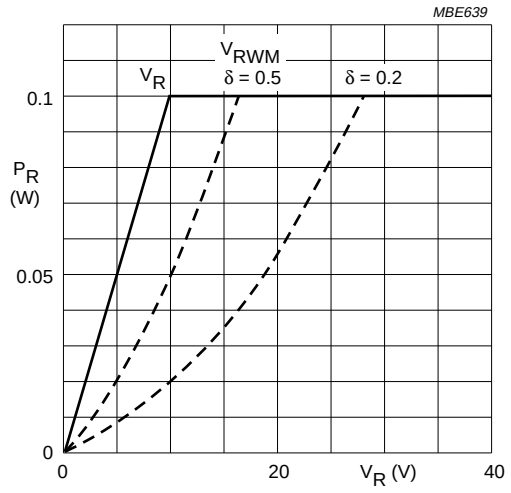
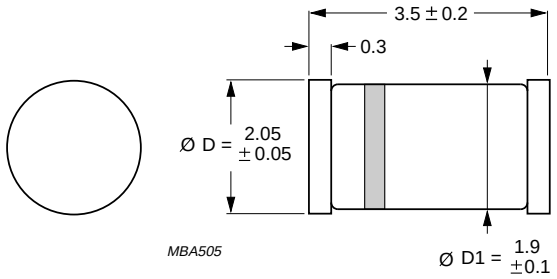


Fig.11 PRLL5819. Reverse power dissipation as a function of reverse voltage (max. values); device mounted; refer to SOD87 standard mounting conditions.

PACKAGE OUTLINE



Dimensions in mm.

Fig.12 SOD87.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.